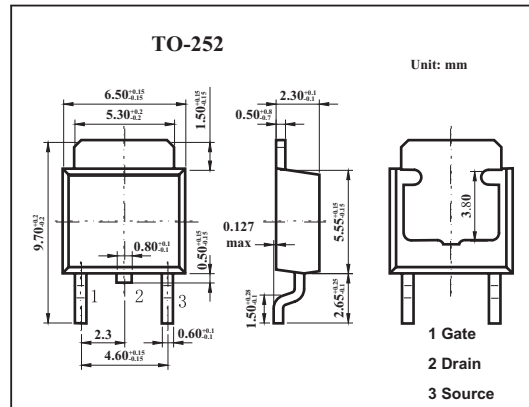


2SK2503

■ Features

- Low on-resistance.
- Fast switching speed.
- Wide SOA (safe operating area).
- Easily designed drive circuits.
- Easy to parallel.



■ Absolute Maximum Ratings Ta = 25°C

| Parameter | Symbol | Rating | Unit |
|-------------------------|-------------------|-------------|------|
| Drain to source voltage | V _{DSS} | 60 | V |
| Gate to source voltage | V _{GSS} | ±20 | V |
| Drain current | I _D | 5 | A |
| | I _{dp} * | 20 | A |
| Power dissipation | P _D | 20 | W |
| Channel temperature | T _{ch} | 150 | °C |
| Storage temperature | T _{stg} | -55 to +150 | °C |

* PW ≤ 10 μs, Duty Cycle ≤ 1%

■ Electrical Characteristics Ta = 25°C

| Parameter | Symbol | Testconditions | Min | Typ | Max | Unit |
|-------------------------------------|---------------------|--|-----|------|-------|------|
| Drain source breakdown voltage | V _{DSS} | I _D =1mA, V _{GS} =0V | 60 | | | V |
| Drain cut-off current | I _{DSS} | V _{DS} =60V, V _{GS} =0 | | | 10 | μA |
| Gate leakage current | I _{GSS} | V _{GS} =±20V, V _{DS} =0 | | | ±100 | nA |
| Gate threshold voltage | V _{GS(th)} | V _{DS} =10V, I _D =1mA | 1.0 | | 2.5 | V |
| Forward transfer admittance | Y _{fs} | V _{DS} =10V, I _D =2.5A | 4.0 | | | S |
| Drain to source on-state resistance | R _{DS(on)} | V _{GS} =10V, I _D =2.5A | | 0.11 | 0.135 | Ω |
| | | V _{GS} =4V, I _D =2.5A | | 0.17 | 0.20 | Ω |
| Input capacitance | C _{iss} | V _{DS} =10V, V _{GS} =0, f=1MHZ | | 520 | | pF |
| Output capacitance | C _{oss} | | | 240 | | pF |
| Reverse transfer capacitance | C _{rss} | | | 100 | | pF |
| Turn-on delay time | t _{on} | | | 5 | | ns |
| Rise time | t _r | I _D =2.5A, V _{GS(on)} =10V, R _G =10Ω, R _L =12Ω, V _{DD} =30V | | 20 | | ns |
| Turn-off delay time | t _{off} | | | 50 | | ns |
| Fall time | t _f | | | 20 | | ns |